

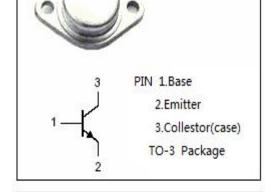
isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 120V (Min)
- · High Current Capability
- Complement to Type 2SB696
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

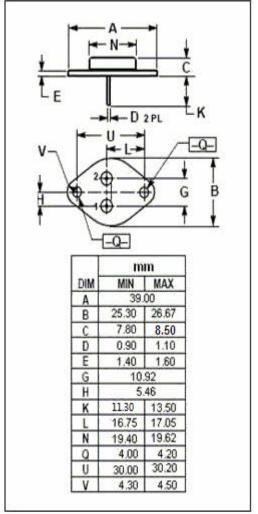
APPLICATIONS

• Designed for AF power amplifier applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	MAX	UNIT
V _{CBO}	Collector-Base Voltage	150	V
V _{CEO}	Collector-Emitter Voltage	120	V
V _{EBO}	Emitter-Base Voltage	6	V
Ic	Collector Current-Continuous	8	Α
Ісм	Collector Current-Peak	12	Α
Pc	Collector Power Dissipation @T _C =25℃	80	W
T _j	Junction Temperature 150		°C
T_{stg}	Storage Temperature Range	-40~150	°C





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2SD732

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA; R _{BE} = ∞	120			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	150			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 0.5A		0.6		V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 1A; V _{CE} = 5V			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 80V; I _E = 0			0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			0.1	mA
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 5V	40		320	
f⊤	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 5V		15		MHz

♦ h_{FE} Classifications

С	D	E	F
40-80	60-120	100-200	160-320

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